Stark E ect of the Au (111) and Cu (111) Surface States

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W e present a low-tem perature scanning tunneling spectroscopy study of the Au (111) and of the Cu (111) surface states showing that their binding energy increases when the tip is approached towards the surface. This result, supported by a one-dimensional model calculation and by a comparison to existing photoem ission spectroscopy measurements, con rms the existence of a tip-induced Stark e ect as previously reported for Ag (111) [L.Lim ot et al., Phys. Rev. Lett. 91, 196801 (2003)], and suggests that this e ect is a general feature of scanning tunneling spectroscopy.

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The presence of the electric eld between the tip of a scanning tunneling m icroscope (STM) and the surface is known to a ect the surface band structure. For instance, when sem iconductors are probed with STM, the electric eld m ay cause a band bending of the surface electronic structure.¹ C ontrary to sem iconductors, the electric eld is e ciently screened in metals by the conduction electrons. Nevertheless, the wave function of surface state electrons is evanescent into the vacuum, and thus it is prone to be a ected by the electric eld. Indeed, scanning tunneling spectroscopy (STS) studies of eld em ission resonance or image states by Becker et al. and by Binnig et al. showed that these states are a ected by a Stark e ect.^{2,3} However, the eld em ission states can only be probed by STM at large tip-sam ple voltages that exceed the tip and sample work functions. The question arises whether the Stark e ect is still sizeable enough to a ect STS spectra even in the tunneling regime where STS experiments are usually performed, i:e:, at voltages considerably lower than the tip and the sam ple work functions. To date, there is a lack of experim ental and theoretical data concerning this issue. In this report, we address this topic by a low-tem perature STS study of the Au (111) and of the Cu (111) Shockley surface states, which represent reference systems for STS. The surface state electrons are an experim ental realization of a quasitwo-dimensional electron gas spatially localized in the topm ost surface layers of a solid, their parabolic energy band lying within surface-projected band gaps of the bulk electronic structure. For this reason, the investigation of surface states especially by m eans of angle-resolved photo electron spectroscopy (ARPES), 4,5,6,7,8,9,10 has a long history. Owing to the atom ic resolution in space and the better-than-m eV resolution in energy, STM and STS can m ap the properties of the surface state electrons by im aging their Friedel oscillations arising from the scattering by adsorption atom s and by step edges,^{11,12,13,14} and by STS m easurem ents perform ed over bare surface terraces and in arti cially engineered nanocavities.^{15,16,17,18} 0 verall, there is a good agreem ent between experiments and

theory.¹⁹ By varying the electric eld of the microscope through the resistance (R) of the junction, from 1G down to $60 \, \text{k}$, we demonstrate that the STS spectra of the Au (111) and of the Cu (111) surface states undergo a downward shift in the tunneling regime. We attribute this observation to a Stark e ect. This result, supported by a one-dimensionalm odel calculation and by a comparison to existing ARPES measurements where the tip is absent, con m sthe previous observation of a Stark e ect in STS of the Aq(111) surface state,²⁰ and suggests that thise ect is a general feature of STS. The m easurem ents were performed in a cryogenic STM working at 10K in ultrahigh vacuum (base pressure below 10⁸ Pa). Weem phasize that the apparatus em ployed is not the one used previously to investigate the Stark e ect of the Ag(111) surface state, i:e:, the present data was acquired using a di erent m icroscope and di erent electronics. The sam ple surfaces were prepared by repeated cycles of argon ion bom bardm ent with subsequent annealing. Tunneling spectroscopy of the di erential conductance (dI=dV) versus the sample voltage was performed by opening the feedback loop in the center of areas of 300 A 300 A where no scattering centers were visible in the topographic in ages. For the Au (111) surface, which exhibits a herringbone reconstruction, 21,22,23,24,25,26,27,28,29 we perform ed spectroscopic measurements on hexagonal-close packed (hcp) and face-centered cubic (fcc) regions of the reconstruction. The di erential conductance was measured by employing a modulation technique where a sinusoidal voltage (with root-mean-square amplitude of 1 2mV and a frequency of 9000 Hz) is superimposed on the tunneling voltage and the current response is measured by a lock-in amplier. In order to ensure data quality over the range of tunneling gap resistances investigated, images of the surface and high-resistance spectra (R 600M) were system atically recorded prior to and after the acquisition of each spectrum, following the procedure introduced in Ref. 20. Since no change was discernible in these images or in these spectra, we conclude that neither a perm anent tip m odi cation nor

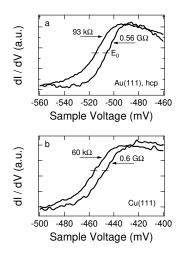


FIG. 1: dI=dV versus sample voltage for: (a) Au(111) (hcp region), (b) Cu(111). The tunneling gaps were set at V = 560 mV, I = 1nA and V = 600 mV, I = 1nA for the right-hand-side spectra in (a) and (b), respectively, whereas the left-hand-side spectra correspond to gap settings of V = 560 mV, I = 6 A and V = 600 mV, I = 10 A, respectively. The spectra are averages of various spectra recorded with di erent tips and at di erent locations of the surface.

a tip-induced dam age of the surface occurred when acquiring spectra in the 60 k - 1 G range. We adhered to the procedure discussed in extenso in Ref. 20 to ensure that artifacts likely to pollute the shift of the spectra are negigible (below 0:5m eV). Figure 1 presents spectra of the surface states of Au (111) (Fig. 1a) and of Cu (111) (Fig. 1b) for the lowest and highest tunneling resistances where STS was performed. The step-like onset of the di erential conductance corresponds to the low band edge, or binding energy, E $_0$ of the surface state electrons. To determ ine E_0 , we employ the geometrical analysis of Ref. 15. For the high resistance spectrum, we extract for Au (111) a binding energy of $E_0 =$ 505 m eV (R = 560 M) and for Cu (111) a binding energy of $E_0 = 445 \text{ meV}$ (R = 600 M), in agreement with prior STS m easurements.¹⁵ A sizeable shift of E $_0$ for both surfaces is clearly visible in Fig. 1. Upon decreasing R to 93k, the binding energy of the Au (111) surface state shifts dow nw ard by 10 m eV, independently on w hether the spectrum is acquired over a hop or a foc region of the herringbone reconstruction (see Fig. 2). Sim ilar to Au (111), the surface state on set of Cu (111) shifts dow n-9 meV when R is decreased to 60 k. No ward by appreciable broadening of the onset is observed. Figure 2 is the quantitative evaluation of the band edge shift of all the recorded spectra (Fig. 2a presents the data for Au (111) (the binding energy values for the fcc (hcp) region are depicted as full (open) circles); the corresponding data for Cu (111) are presented in Fig. 2b). A s show n, the binding energy E₀ of the two surface states undergoes a gradualdownward shift upon decreasing the resistance.

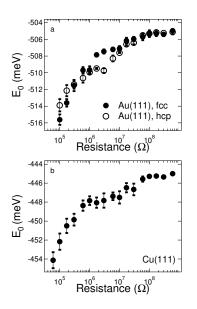


FIG. 2: Surface state binding energy E_0 versus the tunnel junction resistance for: (a) Au (111) (hcp region: solid circles, fcc region: open circles), (b) Cu (111). Each binding energy is the average value of the onset energy extracted from various spectra and the error bar is the corresponding m ean deviation.

For Au (111), the shifts recorded over the hop and the foc regions of Au (111) do not exhibit major di erences, thus the contribution of the Au (111) herringbone reconstruction to the observed shift is negligible. O verall, the shift corresponds for both surfaces to a 2% variation of E₀ for R ranging from 100 k to 1G, lower than the 6% variation observed for the surface state of Ag(111) over the same range of tunneling resistances. Finally, in order to express the dependency of E 0 on the tip displacem ent and to link the data to ourm odel calculation of the shift (presented below), we measured the evolution of R with the tip-surface separation over a distance of 6A which covers the range of resistances of interest. For both surfaces we observe the usual tunneling behavior R / exp(1:025 $^{\rm D}$ =d), where d is the tip-surface distance, with apparent barrier heights of $= (52 \ 02) \text{ eV}$ for Au (111) and of = $(4:7 \ 0:2)$ eV for Cu (111). However, contrary to Au (111), the resistance-versus-displacem ent curve of Cu (111) exhibits a deviation from tunneling behavior for R 200k, indicating that at these resistances the junction is no longer in a tunneling regime; a sim ilar behavior was also observed for Aq(111) when 100 k .²⁰ Sum m arizing the experim ental ndings, R our STS data underline the existence of a dow nw ard shift of the Au (111) and Cu (111) surface state binding energy upon decreasing the tunneling resistance. Since the resistance depends on the the tip-surface distance d, by varying R we also change the electric eld between the tip and the surface (/ 1=d). As for Ag (111), the observed increase of the surface state binding energies is therefore a Stark shift essentially produced by the electric eld of the tunnel junction acting on the energy levels of the

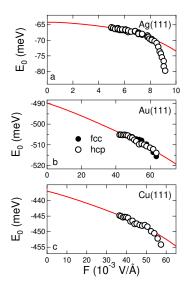


FIG. 3: E_0 versus the electric eld F for (a) Ag(111), (b) Au(111) (hop region: solid circles, for region: open circles), and (c) Cu(111), along with the model calculation of the Stark shifts (solid curves).

surface state of Au (111) and of Cu(111). To emphasize this, we present in Fig. 3 the binding energies of the Au(111) (Fig. 3b) and of the Cu(111) (Fig. 3c) surface states, along with the binding energies of the Ag(111) surface state of R ef. 20 (F ig. 3a), versus the approxim ate am plitude of the electric eld $F = V_0 = d_1^{30}$ where we set eV_0 to the binding energies determ ined by ARPES (see Tab. I). The solid lines in Fig. 3 are the calculated shifts predicted by the one-dim ensionalm odelem ployed in Ref. 20. This model is based on the surface state potential proposed by Chulkov et al.,³¹ but is modi ed to account for the presence of the tip by adding to the potential the linear contribution of the voltage between the tip and the surface, as well as the di erence between the work functions of the tip (t) and the surface (s) to include the contact potential. Furtherm ore, the shape of the im age potential is modi ed to account for multiple in ages in the tip and the surface. The calculation reproduces the data over a range of elds, but not at the highest elds investigated where, as discussed below, an expected discrepancy occurs with the data. The best t for Au (111) is achieved with t = 5.00 eV and s = 5.55 eV, whereas for Cu (111) and for Ag (111) a work function of, respectively, 4:94 eV and 4:56 eV is su cient for both tip and surface (all the values of s are xed to those of Ref. 31). From an experimental point of view, we assume s, because the tip is prepared by controlled tipt surface contacts. The tip apex is therefore covered by substrate material with a high step density. A low ering of the work function of a gold-coated tip by 0:5 eV with respect to the Au (111) work function is consistent with what is observed on vicinal gold surfaces with a high step density.³² On the other hand, since for copper the Sm oluchow skie ect is ten tim es weaker com pared to gold, the

TABLE I: Surface-state binding energies (m eV) for the (111) surfaces of Ag, Au, and Cu obtained by ARPES and by STS.

	Ag(111)	Au (111)	Cu(111)
ARPES ^a	63 1	487 1	435 1
STS (R ! 1)	64 1	490 2	437 1
STS ($R = 500 M$)	66 1	505 1	445 1

^a F.Reinert et al, Phys.Rev.B 63, 115415 (2001).

work function of copper vicinal surfaces is low ered typi-0:05 eV with respect to Cu (111).³³ W e therecally by fore expect the copper-coated tip to yield ts, and for Cu (111) the contribution of the contact potential to the Stark shift can be neglected. From our model calculation, this is also likely for Ag (111). Focusing rst on the low – eld behavior of the Stark shift of Fig. 3, it can be seen that when F is decreased, i:e:, when the tip is retracted, the Stark e ect progressively disappears and E₀ reaches its non-perturbed value. The extrapolation of the model calculations to R ! 1 (F = 0) yields the values of the Stark-free binding energies, which agree rem arkably well with recent ARPES experiments where no electric eld is present (Tab. I). From our STS data, we conclude that even at the lowest feasible tunneling currents which are accessible in experiments, the Stark e ect contribution cannot be elim inated. A sunderlined in Tab. I, because of the tip-induced Stark e ect, the binding energies of the noble m etal surface states in usual STS experim ents are shifted by a few percent com pared to their non-perturbed values. M ore generally, we expect larger Stark shifts for states with wave functions that penetrate further into vacuum than these Shockley surface states. W e now turn to the high-eld Stark e ect. In Figs. 3a and 3c a deviation of the calculated curve from the exper- $10^{3}V = A$ im ental data is observed starting from 8 $10^{-3} V = A$ in in the case of Ag(111) and from 55 the case of Cu (111). Increasing the electric eld above these values leads to an accelerated downward shift of the m easured binding energy as com pared to theory. W e attribute this e ect to the collapse of the constant tipsurface geometry, which is not accounted for in the calculations. It is well known, that at sm all tip-surface distances, i:e:, when R . 100 k , the STM junction is no longer in a tunneling regime, rather in a contact regime where the tip and the surface interact.³⁴ This leads to local modi cations of the tip and of the surface geom etries, which must enhance the electric eld of the STM junction. This conclusion agrees with the fact that the accelerated downward shift for Ag(111) and for Cu(111) occurs concom itantly with the deviation from the exponential tunneling behavior seen in the resistance-versusdisplacem ent curves. We also note that at these resistances, the tip-surface deform ations must be reversible since the images acquired after the low-resistance spectra did not show any irreversible surface modi cation. The interpretation of an enhanced Stark e ect for Cu(111)

and for Ag (111) in term s of a tip-surface geom etry m odi cation, is also consistent with the data of Au (111). In fact, for Au (111) there is no enhanced Stark e ect (the calculated and the experim ental shifts m atch) and an exponential behavior is seen in the resistance-versusdisplacem ent curve of Au (111) down to the lowest resistances probed (R 90 k). In conclusion, we perform ed low-tem perature ST S on the Au (111) and on the Cu (111) surface states for tunneling resistances ranging from 1G

down to 60 k. We observe a downward shift of the surface state binding energy upon decreasing the tip-surface distance (the measurements on the hop and fcc sites of the Au (111) herringbone reconstruction yield a similar shift). This energy shift is attributed to a Stark e ect mainly originating from the tunneling voltage between

- the tip and the surface, as was previously reported for the Ag(111) surface state.²⁰ As for Ag(111), Cu(111) exhibits an enhanced Stark e ect at low resistances, which we associate to the breakdown of the tunneling regime of the STM. The interpretation of the shift in term s of a Stark e ect is supported by a one-dim ensionalm odel calculation, from which we extract Stark-free binding energies close to those determ ined in the ARPES experiments of Ref. 10. The presence of a Stark e ect in reference system s such as the noble m etal surface states, even at usual tunneling parameters, strongly suggests that this e ect is quite common for STM and for STS. J.K., L. L., H. J., and R. B. acknow ledge nancial support by the D eutsche Forschungsgem einschaft, and P. J. by the Swedish R esearch C ouncil.
- ¹ See, for exam ple, M .M cE llistrem, G .H aase, D .Chen, and R .J.H am ers, Phys.Rev.Lett. 70, 2471 (1993).
- ² R.S.Becker, J.A.G obvchenko, and B.S.Swartzentruber, Phys.Rev.Lett. 55, 987 (1985).
- ³ G.Binnig, K.H.Frank, H.Fuchs, N.Garcia, B.Reihl, H. Rohrer, F.Salvan, and A.R.W illiams, Phys.Rev.Lett. 55, 991 (1985).
- ⁴ P.Heimann, H.Neddermeyer, and H.F.Rolo, J.Phys. C 10, L17 (1977).
- ⁵ S.D.Kevan, Phys. Rev. Lett. 50, 526 (1983).
- ⁶ K.Giesen, F.Hage, F.J.Himpsel, J.H.Riess, and W. Steinmann, Phys. Rev. Lett. 55, 300 (1985).
- ⁷ R.Manzke and M. Skibowski, Physica Scripta 31, 2213 (1988).
- ⁸ H.Carstensen, R.Claessen, R.Manzke, and M.Skibowski, Phys.Rev.B 41, 9880 (1990).
- ⁹ J. Fraxedas, H. J. Trodahl, S. Gopalan, L. Ley, and M. Cardona, Phys. Rev. B 41, 10068 (1990).
- ¹⁰ F.Reinert, G.Nicolay, S.Schm idt, D.Ehm, and S.Hufner, Phys.Rev.B 63, 115415 (2001).
- ¹¹ L.C.Davis, M.P.Everson, R.C.Jaklevic, and W.Shen, Phys.Rev.B 43, 3821 (1991).
- ¹² Y.Hasegawa and Ph.Avouris, Phys.Rev.Lett. 71, 1071 (1993).
- ¹³ M.F.Crommie, C.P.Lutz, and D.M.Eigler, Nature (London) 363, 524 (1993).
- ¹⁴ L.Burgi, J. Jeandupeux, H. Brune, and K. Kem, Phys. Rev.Lett. 82, 4516 (1999).
- ¹⁵ J.K liewer, R.Berndt, E.V.Chulkov, V.M.Silkin, P.M. Echenique, and S.Crampin, Science 288, 1399 (2000).
- ¹⁶ H.C.M anoharan, C.P.Lutz, and D.M.Eigler, Nature (London) 403, 512 (2000).
- ¹⁷ J.K liewer, R.Berndt, and S.Cram pin, Phys. Rev. Lett. 85, 4936 (2000).
- ¹⁸ K.-F.Braun and K.-H.Rieder, Phys. Rev. Lett. 88, 96801 (2002).

- ¹⁹ P.M. Echenique, R. Berndt, E.V. Chulkov, Th. Fauster, A.Goldmann, and U.Hofer, accepted in Surf. Sci. Rep. (2003).
- ²⁰ L. Lim ot, T. M aroutian, P. Johansson, and R. Berndt, Phys. Rev. Lett. 91, 196801 (2003).
- ²¹ J.Perdereau, J.P.B iberian, and G.E.Rhead, J.Phys.F (M et.Phys.) 4, 798 (1974).
- ²² H.Melle and E.Menzel, Z.Naturforsch.A 33, 282 (1978).
- ²³ M.A.v.Hove, R.J.Koestner, P.C.Stair, J.P.Biberian, L.L.Kesmodel, I.Bartos, and G.A.Somorjai, Surf.Sci. 103, 189 (1981).
- ²⁴ K.Takayanagiand K.Yagi, Trans. Jpn. Inst. M et. 24, 337 (1983).
- ²⁵ U. Harten, A. M. Lahee, J. P. Toennies, and Ch. W oll, Phys. Rev. Lett. 54, 2619 (1985).
- ²⁶ Ch.W oll, S.Chiang, R.J.W ilson, and P.H.Lippel, Phys. Rev.B 39, 7988 (1989).
- ²⁷ K.G.Huang, D.Gibbs, D.M.Zehner, A.R.Sandy, and S.G.J.Mochrie, Phys. Rev. Lett. 65, 3313 (1990).
- ²⁸ J. V. Barth, H. Brune, G. Ertl, and R. J. Behm, Phys. Rev. B 42, 9307 (1990).
- ²⁹ D.D.Chambliss, R.J.W ilson, and S.Chiang, Phys. Rev. Lett. 66, 1721 (1991).
- ³⁰ Our model calculation yields d 12A for R = 1G .W e employ this reference position to estimate the absolute tipsurface distance. A variation of 1A has only a negligible impact on the analysis of the data, accounted for in the error bars of Tab. I.
- ³¹ E.V.Chulkov, V.M. Silkin, amd P.M. Echenique, Surf. Sci. 437, 330 (1999).
- ³² B.Krahlurban, E.A.Niekisch, and H.Wagner, Surf.Sci. 64, 52 (1977).
- ³³ M.Roth, M.Pickel, J.W ang, M.W einelt, and Th.Fauster, Appl.Phys.B, 74 661 (2002).
- ³⁴ M.Brandbyge et al, Phys.Rev.B 52, 8499 (1995).